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Application Number		10/759,592			
Filing Date		1/16/2004			
First Named Inventor		Jie Liu			
Art Unit		1775			
Examiner Name		Daniel H. Miller			
Attorney Docket Number		062987-0107			
Sheet	1	of	1		

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear

FOREIGN PATENT DOCUMENTS

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NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁶
	B1	LIU et al., "Advances in CN _x Nanotube Growth," Mat. Res. Soc. Symp., Proc., 2003, 772:M2.5.1-M2.5.7.	
	B2	PURETZKY et al., "In situ measurements and modeling of carbon nanotube array growth kinetics during chemical vapor deposition," Appl. Phys., A, 2005, 81:223-240.	
	B3	TERRONES et al., "N-doping and coalescence of carbon nanotubes: synthesis and electronic properties," Appl. Phys. A, 2002, 74:355-361.	
	B4	YUN et al., "Growth Mechanisms of Long Aligned Multiwall Carbon Nanotube Arrays by Water-Assisted Chemical Vapor Deposition," J. Phys. Chem. B, 2006, 110:23920-23925.	

Examiner Signature	Date Considered
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